

Detailed Description

Various embodiments of the present invention will be described in detail with reference to the drawings, where like reference numerals represent like parts and assemblies throughout the several views. Reference to various embodiments does not
5 limit the scope of the invention, which is limited only by the scope of the claims attached hereto. Additionally, any examples set forth in this specification are not intended to be limiting and merely set forth some of the many possible embodiments for the claimed invention.

Throughout the specification and claims, the following terms take at least the
10 meanings explicitly associated herein, unless the context clearly dictates otherwise. The meanings identified below are not intended to limit the terms, but merely provide illustrative examples for the terms. The meaning of "a," "an," and "the" includes plural reference, and the meaning of "in" includes "in" and "on." The term "connected" means a direct electrical connection between the items connected, without any intermediate
15 devices. The phrase "in one embodiment," as used herein does not necessarily refer to the same embodiment, although it may. The term "coupled" means either a direct electrical connection between the items connected, or an indirect connection through one or more passive or active intermediary devices. The term "circuit" means either a single component or a multiplicity of components, either active and/or passive, that are coupled
20 together to provide a desired function. The term "signal" means at least one current, voltage, charge, temperature, data, or other signal.

Briefly stated, a timer circuit is arranged for reduced propagation delay and at low supply voltages. The timer circuit includes a capacitor circuit, a voltage offset circuit, an inverter circuit, and a current source circuit. The current source circuit is arranged to
25 provide a current. Also, the capacitor circuit is arranged to provide a voltage ramp in response to the current. The voltage offset circuit is configured to provide a voltage offset. Further, the current source circuit, the capacitor circuit, and the voltage offset circuit are arranged to provide two voltage ramps that are offset from each other. Additionally, the inverter circuit includes a p-type transistor and an n-type transistor. The
30 p-type transistor is configured to receive one of the two voltage ramps, and the n-type transistor is configured to receive the other of the two voltage ramps.

0). However, the voltage associated with signal VOUT does not change from VDD to 0 instantaneously when logic circuit 130 reaches threshold. Rather, as shown in FIGURE 2, signal VOUT changes from logic one to logic zero after a propagation delay (t_{delay}) has occurred after the voltage associated with signal VIN reaches voltage Vthr.

5 When logic circuit 130 reaches threshold, if $V_{\text{SG}}+V_{\text{TP}}$ of transistor M1 is relatively small and/or $V_{\text{GS}}-V_{\text{TN}}$ of transistor M2 is relatively small, propagation delay t_{delay} can be relatively large. This can particularly be a problem if supply voltage VDD is relatively small. However, by employing voltage offset circuit 120, $V_{\text{SG}}+V_{\text{TP}}$ of transistor M1 and $V_{\text{GS}}-V_{\text{TN}}$ of transistor M2 may be increased when logic circuit 130 is at
10 threshold. Accordingly, employing voltage offset circuit 120 may allow the propagation delay of logic circuit 130 to be decreased for a relatively small supply voltage.

FIGURE 3 shows a block diagram of an embodiment of timer circuit 300. Timer circuit 300 includes current source circuit 310, voltage offset circuit 320, capacitor circuit C1, and inverter circuit 330. Components in timer circuit 300 may operate in a similar
15 manner to similarly named components in circuit 102 of FIGURE 1, and may operate in a different manner in some ways. Similarly, inverter circuit 330 may operate in a similar manner to logic circuit 130 of FIGURE 1, and may operate in a different manner in some ways.

In operation, current source circuit 310 provides current I1. Capacitor circuit C1
20 may be arranged to provide voltage VC1 in response to current I1 such that voltage VC1 is a linearly increasing voltage ramp. Capacitor circuit C1 has a capacitance C. In one embodiment, capacitor circuit C1 is a single capacitor. In another embodiment, capacitor circuit C1 may include two or more capacitors coupled together in series, in parallel, and the like, to provide a total equivalent capacitance of C.

25 Additionally, voltage offset circuit 320 is arranged to provide signals VPIN and VNIN in response to signal VCTL such that signal VNIN is offset relative to signal VPIN. Signal VNIN has a positive voltage offset relative to signal VCTL. In one embodiment, signal VPIN has a negative voltage offset relative to signal VCTL. In other embodiments, signal VPIN may be substantially the same as signal VCTL.

30 FIGURE 4 schematically illustrates an embodiment of timer circuit 400. Components in timer circuit 400 may operate in a similar manner to similarly named

components in timer circuit 300 of FIGURE 3, and may operate in a different manner in some ways. In timer circuit 400, voltage offset circuit 420 includes resistor circuit R1.

In operation, capacitor circuit C1 may be configured to provide signal VPIN in response to current I1 such that signal VPIN is a linearly increasing voltage ramp.

5 Capacitor circuit C1 has a capacitance C.

Additionally, resistor R1 may be arranged to provide signal VNIN such that signal VNIN is substantially given by $VPIN + I1 * R1$. In one embodiment, resistor circuit R1 is a single resistor. In other embodiments, resistor circuit R1 may include one or more resistors coupled together in series, in parallel, and the like.

10 When the threshold of inverter circuit 430 is reached, V_{SG} of transistor M1 is substantially equal to V_{GS} of transistor M2. Therefore, at the threshold of inverter circuit 130, VPIN may be substantially given by $(VDD - I1 * R1) / 2$, and VNIN may be substantially given by $(VDD + I1 * R1) / 2$. If resistor R1 were not included in timer circuit 400, then, at threshold, V_{SG} of transistor M1 and V_{GS} of transistor M2 would both be
15 approximately $VDD / 2$. By including resistor R1 in circuit 430, V_{SG} of transistor M1 and V_{GS} of transistor M2 are both approximately $(I1 * R1) / 2$ greater.

Additionally, $VPIN(t)$ may be substantially given by $I1 * t / C1$, where t is time, and where VPIN is substantially zero at time $t=0$. Also, $VNIN(t)$ may be substantially given by $I1 * t / C + I1 * R1$.

20 Accordingly, the performance of circuit 400 may be roughly similar to that of a circuit that operates with a supply voltage of $VDD + I1 * R1$, even though circuit 400 operates with a supply voltage of VDD. That is, circuit 400 has an “effective” supply voltage of roughly $VDD + I1 * R1$. Employing resistor R1 in timer circuit 400 may substantially improve the stability circuit 400, as well as the propagation delay at low
25 supply voltages.

FIGURE 5 shows a schematic diagram of an embodiment of timer circuit 500. Components in timer circuit 500 may operate in a similar manner to similarly named components in timer circuit 300 of FIGURE 3, and may operate in a different manner in some ways. In timer circuit 500, voltage offset circuit 520 includes capacitor C3. Also,
30 timer circuit 500 includes capacitor C2 in place of capacitor C1 of FIGURE 3. Capacitor C2 may operate in a similar manner to capacitor C1 of FIGURE 3, and may operate in a

different manner in some ways. In one embodiment, capacitor C2 has a capacitance of $2C$, and capacitor C3 has a capacitance of C . In this embodiment, timing circuit 500 has an equivalent timer capacitance of C . In other embodiments, capacitors C2 and C3 may have capacitances other than $2C$ and C . In one embodiment, one or both of capacitor
5 circuits C2 and C3 are each single capacitors. In other embodiments, one or both of capacitor circuits C2 and C3 may include two or more capacitors coupled together in series, in parallel, and the like.

In the embodiment in which timer circuit 500 has an equivalent timer capacitance of C , when inverter circuit 500 reaches threshold, V_{NIN} may be substantially given by
10 $\frac{3}{4} * V_{DD}$, and V_{PIN} may be substantially given by $\frac{1}{4} * V_{DD}$. Also, $V_{PIN}(t)$ may be substantially given by $(I_1 * t) / 2C$, and $V_{NIN}(t)$ may be substantially given by $(3 * I_1 * t) / 2C$. Accordingly, circuit 500 has an “effective” supply voltage of roughly $3 * V_{DD} / 2$, even though circuit 500 actually operates with a supply voltage of V_{DD} .

FIGURE 6 schematically illustrates an embodiment of timer circuit 600.

15 Components in timer circuit 600 may operate in a similar manner to similarly named components in timer circuit 500 of FIGURE 5, and may operate in a different manner in some ways. Timer circuit 600 may further include resistor R2 and transistors M4-M6. In timer circuit 600, capacitor circuit C3 may include capacitors C31 and C32, coupled in parallel. Similarly, capacitor circuit C2 may include capacitors C21-C24, all coupled in
20 parallel. Additionally, inverter circuit 630 may further include transistors M7-M12.

Also, current source 610 may include transistors M13 and M14, arranged as a current mirror. The current mirror may be configured to provide current I_1 in response to current I_{REF} . The sources of transistors M13 and M14 may be coupled to voltage V_{HI} . In one embodiment, voltage V_{HI} is substantially the same as voltage V_{DD} . In another
25 embodiment, voltage V_{HI} is a boost voltage.

Additionally, transistors M4-M6 may be arranged as transistor switches that are enabled if signal S corresponds to an asserted logic level, and disabled if signal S corresponds to a deasserted logic level. If signal S is asserted, transistors M4-M6 may cause capacitor circuits C2 and C3 to discharge, which in turn may cause voltages V_{PIN}
30 and V_{NIN} to return to substantially zero. If signal S is unasserted, transistors M4-M6 may be disabled, which may cause voltages V_{PIN} and V_{NIN} to linearly increase.

The above specification, examples and data provide a description of the manufacture and use of the composition of the invention. Since many embodiments of the invention can be made without departing from the spirit and scope of the invention, the invention also resides in the claims hereinafter appended.